Document Number: MHW1345N

Rev. 3, 5/2006

MHW1345N

10-200 MHz 34.5 dB 800 mW **GENERAL PURPOSE LINEAR AMPLIFIER MODULE**

CASE 1302-01, STYLE 1

General Purpose Linear Amplifier Module

Features

- 34.5 dB Typical Gain @ 100 MHz
- Silicon Bipolar Technology
- Class A Operation
- Typical ITO = +44 dBm @ 200 MHz
- Unconditionally Stable Under All Load Conditions

Applications

- Driver Amplifier in 50 Ohm Systems Requiring High Linearity
- Instrumentation Amplifiers
- Return Path Amplifier on CATV Systems Operating in the 10 to 200 MHz Frequency Range
- Possible Replacement for CA2830C

Description

- 24 Vdc Supply, 10 to 200 MHz, General Purpose Linear Amplifier Module
- Replaced MHW1345. There are no form, fit or function changes with this part replacement.
- **RoHS Compliant**

Table 1. Maximum Ratings

Rating	Symbol	Value	Unit
DC Supply Voltage	V _{CC}	28	Vdc
RF Power Input	P _{in}	+5	dBm
Operating Case Temperature Range	T _C	- 20 to +100	°C
Storage Temperature Range	T _{stg}	- 40 to +100	°C

Table 2. Electrical Characteristics (T_C = 25 $^{\circ}$ C, V_{CC} = 24 V, 50 Ω system unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Frequency Range	BW	10	_	200	MHz
Gain Flatness (f = 10 - 200 MHz)	G _F	_	±0.5	±1	dB
Power Gain (f = 100 MHz)	G _p	33.5	34.5	35.5	dB
Noise Figure, Broadband (f = 200 MHz)	NF	_	3.8	4.5	dB
Power Output — 1 dB Compression (f = 10 - 200 MHz)	P _{1dB}	630	800	_	mW
Power Output — 1 dB Compression (f = 10 - 200 MHz, V _{CC} = 28 V)	P _{1dB}	1000	1260	_	mW
Third Order Intercept (See Figure 2, f ₁ = 200 MHz)	ITO	43	44	_	dBm
Input/Output VSWR (f = 10 - 200 MHz)	VSWR	_	1.5:1	2:1	_
Second Harmonic Distortion (Tone at 100 mW, f _{2H} = 150 MHz)	d _{so}	_	- 60	- 50	dB
Peak Envelope Power (Two Tone Distortion Test — See Figure 2) (f = 10 - 200 MHz @ - 32 dB IMD)	PEP	600	800	_	mW
Supply Current	Icc	270	310	330	mA



Table 3. S-Parameters (Biased at 24 Volts, T = 25°C $Z_0 = 50\Omega$)

Frequency (MHz)	S11		S21		S12		S22	
	Mag	Ang	Mag	Ang	Mag	Ang	Mag	Ang
10	-19.3	45.5	34.6	-0.6	-47.0	2.3	-14.5	76.8
50	-15.6	35.0	34.2	-56.7	-47.5	-30.3	-12.6	45.0
100	-13.2	34.4	33.9	-114	-47.9	-62.9	-10.8	10.7
200	-11.1	30.1	33.5	134	-48.3	-128	-14.9	-42.6

Magnitude in dB, Phase Angle in degrees.

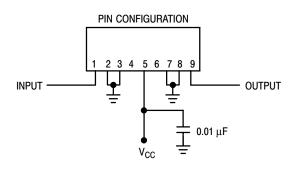
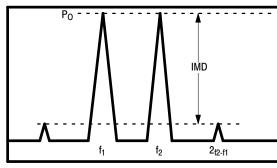


Figure 1. External Connections



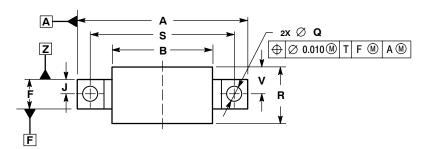
$$\begin{split} &\text{ITO} \,=\, P_{\mbox{\scriptsize O}} \,+\, \frac{\mbox{\scriptsize IMD}}{2} \,\, \mbox{\scriptsize @ IMD} \,>\, 60 \mbox{\scriptsize dB} \\ &\text{\scriptsize PEP} = 4X \, P_{\mbox{\scriptsize O}} \,\, \mbox{\scriptsize @ IMD} = -32 \mbox{\scriptsize dB} \end{split}$$

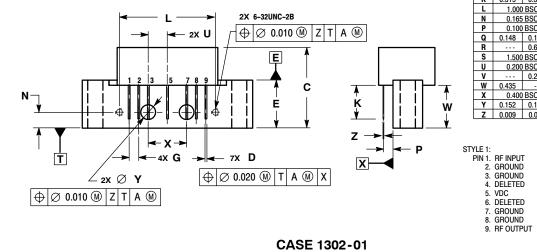
Figure 2. Intermodulation Test



ARCHIVE INFORMATION

PACKAGE DIMENSIONS





CASE 1302-01 ISSUE E

- NOTES:
 1. DIMENSIONS ARE IN INCHES.
 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.

		INC	HES	MILLIMETERS		
	DIM	MIN	MAX	MIN	MAX	
	Α		1.775		45.085	
	В		1.085		27.559	
	С		0.840		21.336	
	D	0.015	0.021	0.381	0.533	
	Е	E 0.465 0.510		11.811	12.954	
	F	F 0.300 0.325		7.62	8.255	
	G	0.100 BSC		2.540 BSC		
	J	0.156	BSC	3.962	2 BSC	
	K	0.315	0.355	8.001	9.017	
	L	1.000	BSC	25.400 BSC		
	N	0.165	BSC	4.191	BSC	
	P	0.100	BSC	2.540	BSC	
	Q	0.148	0.168	3.759	4.267	
	R	R 0.60 S 1.500 BSC			15.24	
				38.100 BSC		
	U	0.200	BSC	5.080	80 BSC	
	V W 0.435		0.250		6.350	
				11.049		
	Х	0.400	BSC	10.16) BSC	
			0.163	3.861	4.140	
			0.011	0.229	0.279	

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